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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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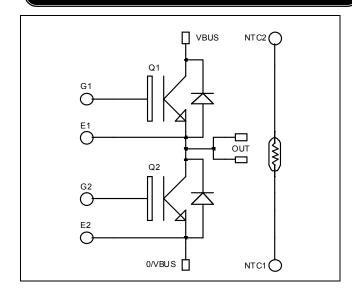


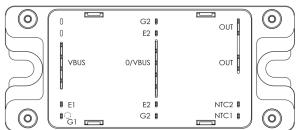




Phase leg High speed Trench + Field Stop IGBT4 Power Module







Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- High speed Trench + Field Stop IGBT 4 Technology
 - Low voltage drop
 - Low leakage current
 - Low switching losses
- Kelvin emitter for easy drive
- Very low stray inductance
- Lead frames for power connections
- Internal thermistor for temperature monitoring

Benefits

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive T_C of V_{CEsat}
- Low profile
- RoHS Compliant

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings (Per IGBT)

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Voltage		1200	V
Ţ	Continuous Collector Current	$T_C = 25$ °C	250	
I_{C}	Continuous Collector Current $\frac{T_C = 80^{\circ}}{T_C = 80^{\circ}}$	$T_C = 80$ °C	150	Α
I_{CM}	Pulsed Collector Current	$T_C = 25$ °C	480	
$ m V_{GE}$	Gate – Emitter Voltage		±20	V
P_{D}	Power Dissipation		750	W

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



Electrical Characteristics (Per IGBT)

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1200V$				100	μΑ
V _{CE(sat)}	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$	1.78	2.05	2.4	V
		$I_C = 150A$ $T_j = 150^{\circ}C$			2.6		V
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 5.2 \text{ mA}$		5.3	5.8	6.3	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				240	nA

Dynamic Characteristics (Per IGBT)

Symbol	Characteristic	Test Condition	ns	Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			8.8		
C_{oes}	Output Capacitance	$V_{CE} = 25V$			0.5		nF
C_{res}	Reverse Transfer Capacitance	f = 1MHz	f = 1MHz		0.45		
Q_{G}	Gate charge	$V_{GE} = 15V, I_{C} = 150A$ $V_{CE} = 960V$			645		nC
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			30		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			57		ns
T _{d(off)}	Turn-off Delay Time	$V_{Bus} = 600V$ $I_{C} = 150A$			290		
T_{f}	Fall Time	$R_G = 3.5\Omega$	_		16		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C)			30		
$T_{\rm r}$	Rise Time	$V_{GE} = \pm 15V$			49		l
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm C} = 150A$	$V_{\text{Bus}} = 600V$ $I_{\text{C}} = 150A$ $R_{\text{G}} = 3.5\Omega$		366		ns
T_{f}	Fall Time	$R_G = 3.5\Omega$			48		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 600V$	$T_j = 150$ °C		13		mJ
E_{off}	Turn off Energy	$I_C = 150A$ $R_G = 3.5\Omega$	$T_j = 150$ °C		8		1113
R_G	Integrated gate resistor				5		Ω
I_{sc}	Short Circuit data	$V_{GE} \le 15V$; $V_{Bus} = 600V$ $t_p \le 10\mu s$; $T_j = 150^{\circ}C$			525		A
R_{thJC}	Junction to Case Thermal Resistance					0.20	°C/W

Diode ratings and characteristics (per diode)

Symbol	Characteristic Test Conditions		Min	Typ	Max	Unit	
V_{RRM}	Peak Repetitive Reverse Voltage					1200	V
I_{RM}	Reverse Leakage Current	V _R =1200V				400	μΑ
I_F	DC Forward Current		Tc = 60°C		120		A
		$I_F = 120A$			2.6	3.5	V
$V_{\rm F}$	Diode Forward Voltage	$I_F = 240A$			3.2		
		$I_F = 120A$	$T_{j} = 125^{\circ}C$		1.8		
	D Time	$I_{\rm F} = 120 A$	$T_j = 25$ °C		300		***
t_{rr}	Reverse Recovery Time		11i - 123 C		380		ns
0	Reverse Recovery Charge	$\begin{array}{c} V_R = 800V \\ di/dt = 800A/\mu s \end{array}$	$T_j = 25^{\circ}C$		1.44		
Q _{rr}			$T_j = 125^{\circ}C$		6.8		μС
R_{thJC}	Junction to Case Thermal Resistance					0.33	°C/W



$Temperature \ sensor \ NTC \ (see \ application \ note \ APT0406 \ on \ www.microsemi.com).$

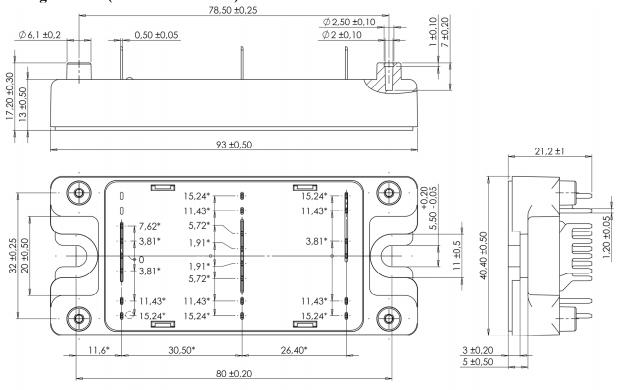
Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C	istance @ 25°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
$B_{25/85}$	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		$T_C=100$ °C		4		%

$$R_{T} = \frac{R_{25}}{\exp \left[\frac{1}{B_{25/85}} \left(\frac{1}{T_{-1}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
T_{J}	Operating junction temperature range			-40	175	
T_{JOP}	Recommended junction temperature under switching conditions			-40	T _J max -25	°C
T_{STG}	Storage Temperature Range			-40	125	C
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M5	2.5	4.7	N.m
Wt	Package Weight				160	g

Package outline (dimensions in mm)

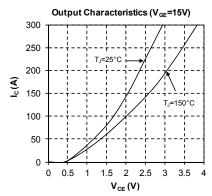


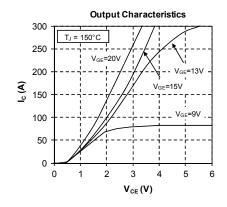
ALL DIMENSIONS MARKED "*" ARE TOLERANCED AS : + Ø 1

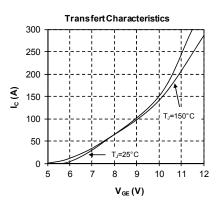
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

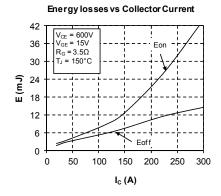


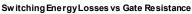
Typical performance curve

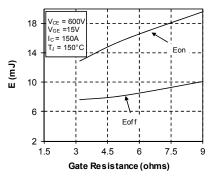


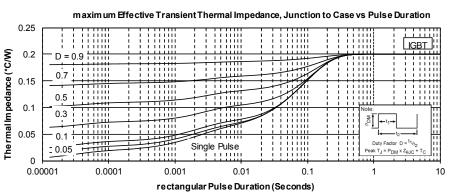








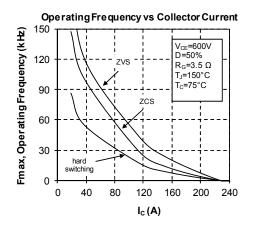


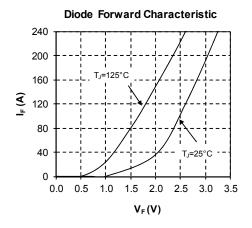


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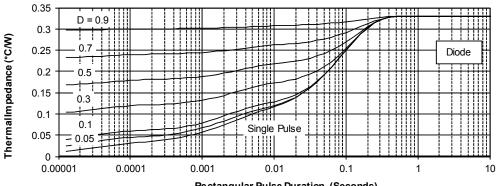


Power Matters.™





maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration



Rectangular Pulse Duration (Seconds)



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